

Photocurrent Spectroscopy of Perovskite Solar Cells Over a Wide Temperature Range from 15 K to 350 K

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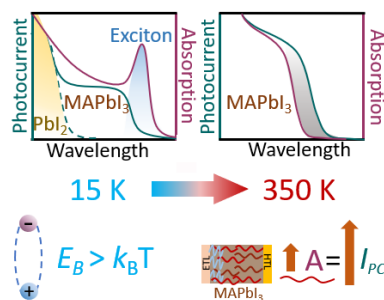
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Abstract

Solar cells based on metal halide perovskite thin films show great promise for energy generation in a range of environments from terrestrial installations to space applications. Here we assess the device characteristics of the prototypical perovskite solar cells based on methylammonium lead triiodide ($\text{CH}_3\text{NH}_3\text{PbI}_3$) over a broad temperature range from 15 K to 350 K (-252°C to 77°C). For these devices, we observe a peak in the short-circuit current density and open-circuit voltage at 200 K (-73°C) with decent operation maintained up to 350 K. We identify the clear signature of crystalline PbI_2 contributing directly to the low-temperature photocurrent spectra, showing that PbI_2 plays an active role (beyond passivation) in $\text{CH}_3\text{NH}_3\text{PbI}_3$ solar cells. Finally we observe a blue-shift in the photocurrent spectrum with respect to the absorption spectrum at low temperature (15 K), allowing us to extract a lower limit on the exciton binding energy of 9.1 meV for $\text{CH}_3\text{NH}_3\text{PbI}_3$.

TOC



Photovoltaic devices containing a photoactive thin film of metal-halide perovskites have now achieved power conversion efficiencies above 22%,¹ while the prospect of multi-junction perovskite cells promises even higher efficiencies.² High-performance solar cells are sought after for power generation in extreme environments such as space. However, to be suitable for use e.g. on satellites, solar cells must be able to operate over a wide temperature range typically from -100°C to 125°C (173 K – 398 K).³ An in-depth understanding of perovskite solar cell operation over a wide range of temperatures is therefore crucial for the evaluation of their use in such locations. Methylammonium lead triiodide (MAPbI₃) is a prototypical metal-halide perovskite material whose use in solar cells has been extensively explored over the past 5 years. MAPbI₃ is well suited to photovoltaic applications owing to favourable intrinsic properties such as a high absorption coefficient for visible light, long charge-carrier diffusion lengths, high charge mobilities, and a benign defect chemistry.⁴⁻⁶ Furthermore, the processing techniques available for thin-film fabrication of MAPbI₃ are truly versatile and offer the prospect of low-cost large-area photovoltaics. Spin-coating of a precursor solution containing PbI₂ and methylammonium iodide (MAI) has been the most popular of various solution processing techniques.⁷⁻⁹ Whilst spin-coating offers a low temperature method of processing, the thin films can suffer from the formation of pin-holes and the choice of solvent can greatly affect film quality.⁸ Thermal evaporation of the precursor materials, on the other hand, does not require extensive use of solvents and can reproducibly yield pin-hole free perovskite thin films, suitable for large area device fabrication.¹⁰⁻
¹² In addition, the highest power conversion efficiency (PCE) for a MAPbI₃ based solar cell (20.3%) to date was achieved via a thermally evaporated MAPbI₃ active layer, which offers promise for facile manufacturing and commercialization of perovskite solar cells.¹³ Both fabrication processes have shown that the perovskite thin films can be affected by any remnant

precursors such as PbI_2 or MAI.^{14,15} Recently, perovskite solar cells consisting of remnant PbI_2 in the perovskite thin film, show excellent PCE of 21.6%.¹⁵ However, detailed analysis on the opto-electronic role of the remnant PbI_2 is not fully understood.

We have utilized the sensitive technique of Fourier transform photocurrent spectroscopy (FTPS) combined with current-voltage (J-V) measurements and absorption spectroscopy to assess the viability of MAPbI_3 solar cells over a temperature range from 15 K to 350 K. The device characteristics, short-circuit current density and open-circuit voltage, was optimal at 200 K, and devices operated well up to 350 K. However, a dramatic drop in photocurrent was observed for temperatures lower than 200 K, with photo-currents and -voltages dropping rapidly towards very low temperatures (15 K). Interestingly, at low temperatures we observe a characteristic contribution of PbI_2 in the MAPbI_3 device photocurrent spectra, which we identify by comparison with a PbI_2 -only device with the same architecture. Moreover, we find that there is a discrepancy between the spectral onset of absorption and photocurrent (i) at low temperature, owing to the formation of excitons (ii) around the orthorhombic-tetragonal phase transition, as a result of mixed phases and (iii) at high temperature, because of enhanced collection of charge-carriers generated by longer wavelength light.

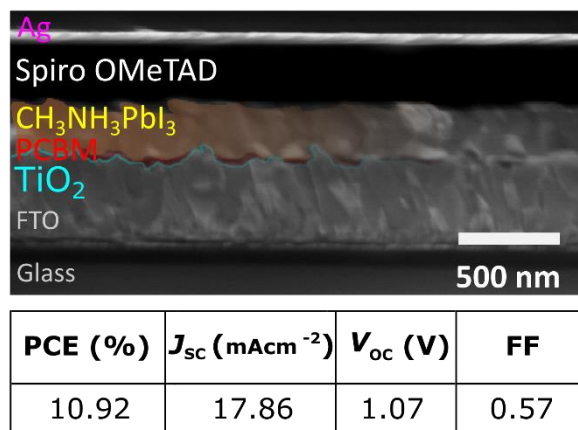


Figure 1. SEM image showing the device structure used in this study, with the current-voltage characteristics measured under 1 sun illumination (AM 1.5G, 100 mW cm⁻²).

Figure 1 shows a cross-sectional scanning electron microscopy image of the device structure used for this study. The device was fabricated on a fluorinated-tin-oxide (FTO) coated glass substrate. It consisted of a dual TiO₂-PCBM electron extraction layer upon which the perovskite MAPbI₃ was deposited via co-evaporation of MAI and PbI₂. A hole extraction layer of 2,2',7,7'-Tetrakis[N,N-di(4-methoxyphenyl)amino]-9,9'-spirobifluorene] (Spiro OMeTAD) was spin-coated over the perovskite prior to thermal evaporation of a silver contact (full details of the device fabrication are provided in the Supporting Information). We have shown previously that this architecture produces high quality perovskite thin films and devices with minimal current-voltage hysteresis and high stabilized power output.¹⁶ The devices were slowly cooled down to 4 K and then characterized as the temperature was increased incrementally. For all measurements, a tungsten halogen lamp was used as the light source.

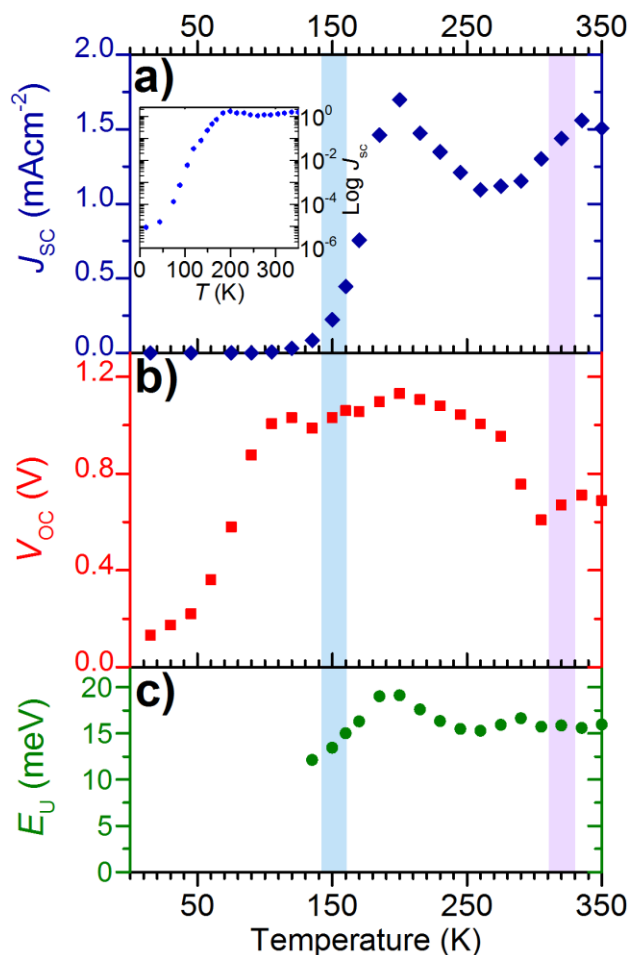


Figure 2. a) The temperature dependence of the short-circuit current density for the MAPbI₃ device, with the inset showing the J_{sc} in a semi-logarithmic scale. b) The temperature dependence of the open-circuit voltage for the same device c) The temperature dependence of the Urbach energy (E_u) for the device derived from fits to external quantum efficiency spectra (as described in the SI). In-situ temperature-dependent measurements were carried out using a tungsten halogen lamp with a light intensity of 0.29 sun. The shaded blue area shows the low-temperature phase transition from an orthorhombic to a tetragonal crystal structure.^{17,18} The shaded lilac area shows the high-temperature phase transition from the tetragonal to the cubic perovskite crystal

structure.^{17,19} Temperature-dependent device characteristics of additional devices are presented in the Supporting Information (SI).

To assess the device characteristics as a function of temperature, in-situ short-circuit current density (J_{sc}) and open-circuit voltage (V_{oc}) of the MAPbI₃ device were measured between 15 K and 350 K, with the results shown in Figure 2a and 2b respectively. The temperature dependence of the V_{oc} incorporates two different regimes, one above and one below 200 K, as observed previously when MAPbI₃ based devices had been cooled to 80 K.^{20–24} The V_{oc} increases with temperature from 15 K and peaks at a value of 1.13 V at 200 K. The J_{sc} , shows an even steeper increase in over 5 orders of magnitude with temperature, also peaking at 200 K. For temperatures higher than 200 K, the V_{oc} , decreases again, similar to observations made for in silicon and organic solar cells,^{25–28} for which the effect has been attributed to the quasi-Fermi levels of the Boltzmann-like electron and hole populations moving closer together as the temperature is increased.^{27,29,30}

In order to evaluate the effect of temperature-mediated changes in the structural disorder of the MAPbI₃ perovskite layer, we extracted the Urbach energy (E_u) from the photocurrent spectra.^{31–33} Figure 2c shows the dependence of E_u (and hence disorder) as a function of temperature. To allow correlation with structural changes, we also indicate in shaded bars the temperature regions where MAPbI₃ is known to undertake structural phase transitions, i.e. from orthorhombic to tetragonal at 140-160 K and from tetragonal to cubic near 310-330 K.^{17–19} In the temperature region for which MAPbI₃ exists in the tetragonal crystal structure, E_u exhibits a minimum value of 12.1 meV at 135 K, which rises to a maximum value of $E_u = 19.1$ meV at 200 K and then decreases again to $E_u = 16.7$ meV at room temperature (290 K). In the cubic phase, the Urbach energy was found to be

near 16 meV and insensitive to temperature. It was not possible to obtain E_u in the orthorhombic phase owing to the co-existence of small tetragonal domains.¹⁸

While thermal energy can play a direct role in dynamic structural disorder,^{34,35} the non-monotonic trend in E_u indicates that this is unlikely to be the major cause of the energetic broadening of the photocurrent onset here. Rather it seems that additional changes with temperature, as for example strain, contribute to disorder. It is also interesting to note that the temperature dependence of the device J_{sc} and V_{oc} is not well correlated with the temperature dependence of the Urbach energy, indicating that disorder in the perovskite layer is unlikely to be the main factor limiting the low-temperature J_{sc} and V_{oc} of MAPbI₃ solar cells. We therefore suggest that the pronounced temperature variation in the J_{sc} and V_{oc} may in part be attributed to factors unrelated to the MAPbI₃ layer, such as the charge-extraction performance of the electron- and hole-extractor layers. Hybrid perovskites such as MAPbI₃ have been found to exhibit enhanced charge-carrier mobilities with lower temperature,¹⁷ as a result of reduced electron-phonon coupling,³⁶ compatible with band transport within a large-polaron picture.³⁷ However, charge-transport in organic semiconductors and disordered crystalline solids, such as the TiO₂, PCBM and Spiro OMeTAD materials typically used for charge-extraction for perovskite devices, is typically governed by hopping transport that may be thermally activated.^{38,39} Jacobsson et al observed a significant increase in series resistance from current-voltage scans, as the temperature decreased, confirming that the reduction in the conductivity of the organic charge transport layers leads to a decrease in J_{sc} .²² Therefore, the sharp drop in J_{sc} , as the temperature is lowered past 150 K (Fig. 2a) may potentially be partly remediated by use of alternative charge-extraction materials that exhibit band-transport at low temperatures, similar to MAPbI₃.

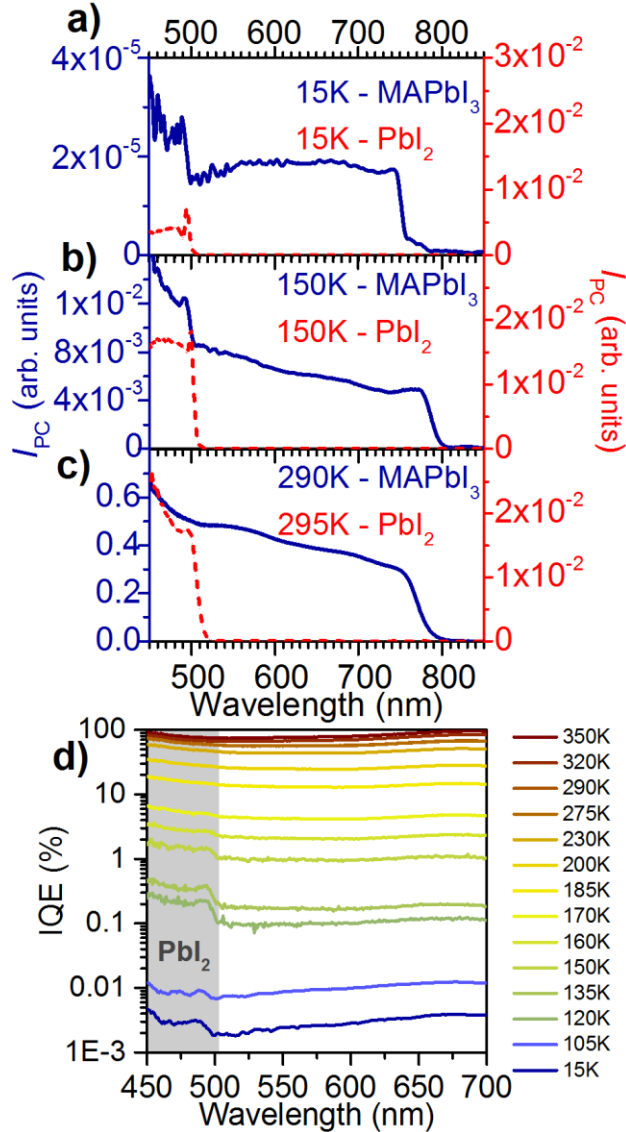


Figure 3. a-c) Photocurrent spectra of a MAPbI₃ device as shown in Figure 1a (blue) and a PbI₂ device (red-dashed) which has the same architecture as the one shown in Figure 1a except that MAPbI₃ is replaced with PbI₂ at a) 15 K, b) 150 K and c) 290 K. The MAPbI₃ device at 15 K and 150 K shows significant PbI₂ contribution to the photocurrent (I_{PC}), between 507 nm and 526 nm. Notably, the MAPbI₃ photocurrent increases by 4 orders of magnitude from 15 K to 290 K, whereas the increase of PbI₂ photocurrent is smaller. d) Internal quantum efficiency (IQE) spectra of the MAPbI₃ device from 15 K to 350 K. At low temperatures, the PbI₂ contribution to the

photocurrent is clearly visible. Notably, the IQE approaches 100% at high temperatures. Temperature-dependent photocurrent spectra of additional devices are presented in the Supporting Information (SI).

We are further able to use temperature-dependent measurements of photocurrent spectra to elucidate the role of excess of PbI_2 in the performance of MAPbI_3 solar cells. A slight excess of PbI_2 in such devices has been shown previously to enhance the PCE.^{15,40} It has been postulated that PbI_2 provides a crystalline framework which increases the crystal quality of MAPbI_3 .⁴¹ Furthermore, the presence of PbI_2 at grain boundaries has been found to be beneficial for device PCE.⁴² However, the contribution of PbI_2 in to overall opto-electronic properties of the solar cell is still unclear. Room temperature measurements aimed to detect the photocurrent generated by PbI_2 have proven to be difficult as the high absorption coefficient of MAPbI_3 at the 2.35 eV photon energy¹⁴ ($\lambda=528$ nm) masks any contribution from PbI_2 .⁴³

Figures 3 a-c) show snapshots of the photocurrent spectra of the MAPbI_3 device at 15 K, 150 K and 290 K (blue solid lines). The spectra clearly show an energetic narrowing of the MAPbI_3 photocurrent onset from 290 K to 15 K as a result of reduced electron-phonon coupling (thermal broadening).³⁶ In addition, the magnitude of the photocurrent I_{PC} increases substantially as the temperature is increased, in agreement with the already discussed behaviour of the total current density, J_{sc} , observed in the current-voltage device characteristics (Figure 2). Interestingly, at low temperatures (15 K) an additional, sharp onset in photocurrent can be observed at 507 nm in the photocurrent spectra for the MAPbI_3 device (Figure 3a). This onset exhibits a red-shift with increasing temperature, reaching 510 nm at 150 K as shown in Figure 3b. The spectral position of

the onset and the red-shift are comparable to those reported for the absorption onset of PbI_2 .³⁵ Therefore, to verify that this contribution to the photocurrent indeed originates from PbI_2 , we fabricated a photovoltaic device for which the MAPbI_3 layer was replaced by a PbI_2 layer. The photocurrent spectra of the PbI_2 -only device at 15 K, 150 K and 295 K are shown in Figure 3a-c as red dashed lines. The rise in photocurrent from the PbI_2 devices (red dashed lines) exactly matches the onset seen in the MAPbI_3 devices (solid blue lines) at 507 nm and 510 nm in Figure 3a and 3b, confirming the origin from PbI_2 . We note that the presence of remnant crystalline PbI_2 in our MAPbI_3 layers is also supported by X-ray diffraction pattern (Figure S10). At room temperature (Figure 3c), there is no obvious signature of a PbI_2 photocurrent onset in the MAPbI_3 device (blue line), most likely because the PbI_2 photocurrent is overwhelmed by the much stronger perovskite photocurrent at this temperature. Indeed, our photocurrent spectra for the PbI_2 -only device (Figure 3, red dashed lines) clearly show that it can sustain a decent photocurrent between room temperature and 150 K that decreases as the temperature is reduced towards 15 K.

These results show that any remnant PbI_2 in the MAPbI_3 is able to play an active photocurrent generation role, even under normal operating conditions. Importantly, the MAPbI_3 device incorporates significantly less PbI_2 than MAPbI_3 , yet it shows a clear signature in the photocurrent spectra at 510 nm. Additionally, between 160 K and 120 K, the internal quantum efficiency (IQE) spectra for the MAPbI_3 perovskite solar cell (Figure 3d) are no longer flat, with higher IQE values at photon energies above 2.43 eV ($\lambda < 510\text{nm}$). This demonstrates that the remnant PbI_2 becomes more efficient at converting absorbed light into photocurrent than MAPbI_3 . However, below 120 K the IQE spectra show a simultaneous decrease in IQE from both the PbI_2 and MAPbI_3 . As mentioned earlier, this may be due to the loss in functionality of the organic charge transport layer, due to an increase in series resistance at such low temperatures.²²

Our observation of photogenerated current from PbI_2 networks within MAPbI_3 helps explain previous reports that MAPbI_3 with a slight excess of PbI_2 improves solar cell performance.^{15,40,41,44} Furthermore, Shih et al. have shown that MAPbI_3 devices with excess PbI_2 perform better when the PbI_2 is on the surface of the MAPbI_3 perovskite grain.⁴⁵ Based on the collective data presented, there are two processes that could occur, either concurrently or separately to explain the PbI_2 signal shown in figure 3. Firstly, there could be a homogenous network of PbI_2 , through which photogenerated charge-carriers can be transported and then collected at electron and hole selective layers, which is possible as shown by the PbI_2 -only device. Secondly as Holovský et al have postulated, PbI_2 may create a type II heterojunction with the MAPbI_3 , making it energetically more favourable for the holes to be transported into the MAPbI_3 and electrons to be transported into the PbI_2 .^{45,46} However, this process is thermally activated,⁴⁶ hence at low temperatures it will not be as effective. Our results imply that at low temperature, remnant PbI_2 in a MAPbI_3 device can produce photocurrent independent of MAPbI_3 and at room temperature PbI_2 is also capable of generating photocurrent. To understand the exact origin of the photocurrent observed of PbI_2 at different temperatures, in MAPbI_3 thin film devices, would require detailed investigation of the interface between MAPbI_3 and PbI_2 .

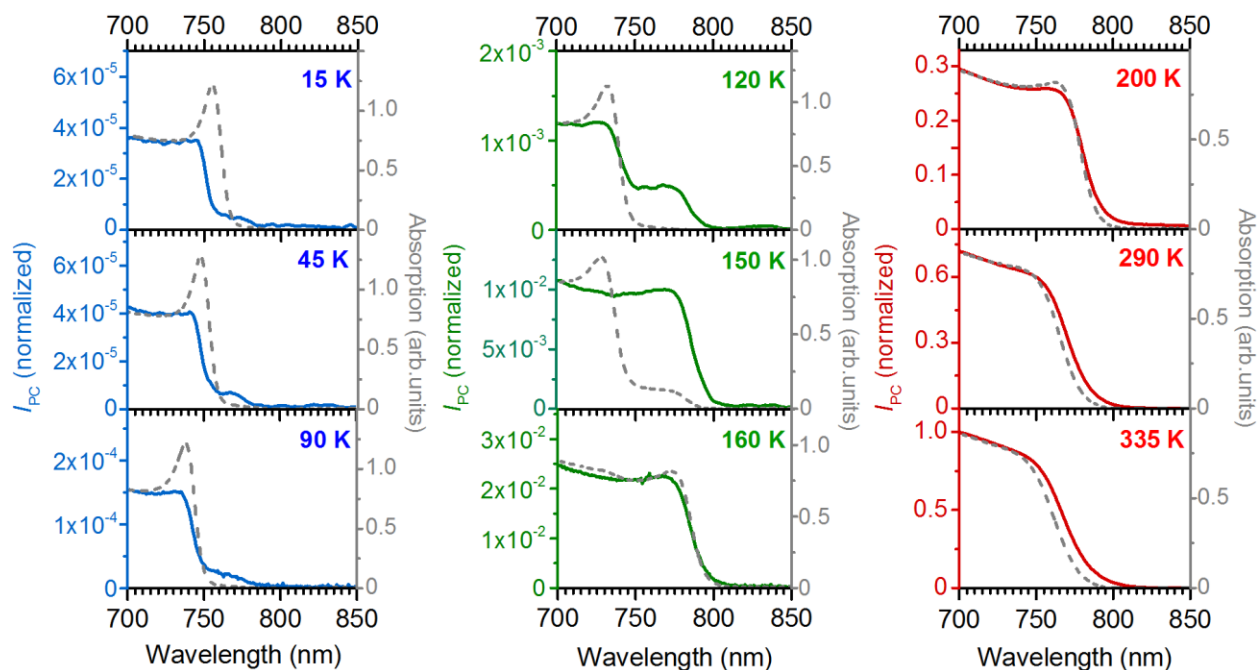


Figure 4. Temperature dependence of the photocurrent (I_{PC}) and absorption onset (dashed line) of the MAPbI₃ device. Here the reflection corrected absorption is of the full device architecture shown in Figure 1 without the Ag electrode. The photocurrent spectra were spectrally corrected using a calibrated silicon solar cell and normalized with respect to the 335 K spectrum. All measurements were made using a tungsten halogen light source. Full photocurrent spectra and absorption spectra can be found in Figure S1-S4 of the Supporting Information (SI)

We may further deduce information on the operation of the MAPbI₃ photovoltaic device by contrasting the temperature-dependent photocurrent and absorption near their onsets (Figure 4). For this purpose, absorption spectra were taken of a film whose architecture resembles that of the device shown in Figure 1, but without the silver electrode. We are able to identify three different regimes of contrasting behaviour. Over the temperature range of 120-160 K (Figure 4b), we observe a significant blue-shift in the absorption spectrum which is characteristic of the tetragonal

to orthorhombic phase transition in MAPbI₃, as previously observed in isolated MAPbI₃ films.¹⁷ However, the photocurrent onset over this range shows that MAPbI₃ retains remnant tetragonal phase in the device that evidently supports an effective photocurrent. Even though the absorption spectra only indicate a small quantity of remnant tetragonal MAPbI₃, a significant amount of red-shifted photocurrent onset can be observed near the energy associated with the band-gap of the tetragonal phase. Such remnants of the tetragonal phase MAPbI₃, must therefore be able to form a crystalline network that allows for photogenerated charges to be extracted at low temperatures. Figure 4a shows that in the temperature range from 15-90 K, the photocurrent onsets become dominated by a trade-off between free-charge and exciton formation. In this temperature range, there is a significant blue shift of the photocurrent onset compared to the absorption onset and the absorption onset shows notable excitonic absorption features. Therefore, in a device that is under no bias, i.e. under short circuit conditions, there would be negligible photocurrent contribution from dissociated excitons unless the thermal energy exceeds the exciton binding energy.⁴⁷ Thus, by comparing the peak of the exciton and the onset of photocurrent at low temperature, as shown in Figure S9, we can estimate a lower bound on the exciton binding energy (E_B) at 15 K to be 9.1 meV, which is consistent with previous magneto-optical experiments which found a value of $E_B = 16$ meV at 4 K.⁴⁷ In contrast, for temperatures above 160 K, the photocurrent onset first overlaps with the absorption onset, then even shifts to slightly longer wavelength (Figure 4c). Hence in this temperature range, photoexcitation yields mostly free charges, as confirmed by our Saha-Langmuir analysis (presented in Figure S7).^{48,49} At temperatures above 160 K, excitons have sufficient thermal energy to dissociate, allowing photocurrent to be generated from dissociated electrons and holes. Curiously, we find that the onset of the photocurrent is slightly red-shifted in relation to the onset of the absorption for temperature above 290 K, which we attribute to an optical cavity effect

within the perovskite multilayer device.^{50–52} Because the absorption coefficient of MAPbI₃ is high for photons well above its bandgap, a high charge-carrier density is photogenerated mainly on the side of the perovskite layer closest to the semi-transparent contact (FTO).^{50,53} However, longer-wavelength photons near the band-edge will generate a much more uniform charge density profile through the MAPbI₃ layer, and it has been observed previously that uniform charge distributions can result in more effective collection of photocurrent in MAPbI₃ compared with when electron-hole generation is concentrated close to just one MAPbI₃ interface of a planar heterojunction device.^{50,51,54} Thus, the photocurrent spectra exhibit an enhanced contribution towards the low-energy side of the perovskite bandgap. Therefore, the correlation between photocurrent and absorption spectra provides an illuminating insight into the mechanisms by which absorbed photons are converted to photocurrent.

In conclusion, the temperature-dependent J_{sc} and V_{oc} for a MAPbI₃ solar cell have been tracked from 15 K to 350 K. We observe that both the J_{sc} and V_{oc} peak near 200 K, where after they deteriorate steeply at lower temperatures, but only decreasing gradually towards higher temperatures. We have probed the device with the highly sensitive technique of Fourier transform photocurrent spectroscopy to understand the temperature dependence of the photocurrent spectra. By comparing photocurrent spectroscopy and absorption spectroscopy on the same solar cell architecture we estimate the exciton binding energy for MAPbI₃ to be greater than 9.1 meV at low temperature, and show that at higher temperatures, low-energy photons that generate uniform charge-density profiles dominate the photocurrent onset. Furthermore, photocurrent spectroscopy has proven a vital tool for understanding the influence of remnant precursors in the perovskite to the total device photocurrent. We show that PbI₂ may contribute to the total photocurrent of the device, hinting at the role of remnant PbI₂ in the MAPbI₃ thin films. Overall, MAPbI₃ solar cells

have shown optimal device parameters at -73°C , which shows that only small improvements may be required in the device architecture to render these solar cells a viable, cheaper alternative for space applications. With the advent of perovskite semiconductors consisting of many mixtures of cations, metals and halides, further investigation will be helpful to see how compositional differences, as well as changes in charge extraction layer materials, may affect the temperature-dependent device performance.

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Notes

The authors declare no competing financial interest.

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Supporting Information

Details on device fabrication, Fourier Transform Photocurrent Spectroscopy, X-Ray Diffraction, Scanning Electron Microscopy, Fourier Transform Infrared Spectroscopy, further temperature dependent measurements, Urbach energy fits, device performance metrics and the fraction of free charges vs excitons can be found in the Supporting Information (SI).

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